
	<h2>SIA813DJ-T1-GE3</h2>
	<p><b>Hersteller-Teilenummer:</b> SIA813DJ-T1-GE3</p> <p><b>Hersteller / Marke:</b> Vishay / Siliconix</p> <p><b>Teil der Beschreibung:</b> MOSFET P-CH 20V 4.5A SC70-6</p> <p><b>Datenblätter:</b>  <a href="#">SIA813DJ-T1-GE3.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 9000 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	SIA813DJ-T1-GE3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET P-CH 20V 4.5A SC70-6
Kategorie	<a href="#">Diskrete Halbleiterprodukte</a> > <a href="#">Transistoren-FETs</a> ,
Teilstatus	9000 pcs Stock
Serie	LITTLE FOOT®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	PowerPAK® SC-70-6 Dual
Supplier Device-Gehäuse	PowerPAK® SC-70-6 Dual
Verlustleistung (max)	1.9W (Ta), 6.5W (Tc)
Typ FET	P-Channel
FET-Merkmal	Schottky Diode (Isolated)
Drain-Source-Spannung (Vdss)	20V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	4.5A (Tc)
Rds On (Max) @ Id, Vgs	94 mOhm @ 2.8A, 4.5V
VGS (th) (Max) @ Id	1V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	13nC @ 8V
Eingabekapazität (Ciss) (Max) @ Vds	355pF @ 10V
Verpackung	Tape & Reel (TR)








































SIA813DJ-T1-GE3 ist neu im Original. Suche SIA813DJ-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SIA813DJ-T1-GE3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SIA813DJ-T1-GE3: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>SIA811DJ-T1-E3</b> Electro-Films (EFI) / Vishay MOSFET P-CH 20V 4.5A SC70-6</p>	 <p><b>SIA814DJ-T1-GE3</b> Vishay / Siliconix MOSFET N-CH 30V 4.5A SC70-6</p>	 <p><b>SIA811DJ-T1-GE3</b> Electro-Films (EFI) / Vishay MOSFET P-CH 20V 4.5A SC70-6</p>	 <p><b>SIA817EDJ-T1-GE3</b> Electro-Films (EFI) / Vishay MOSFET P-CH 30V 4.5A SC70-6</p>
 <p><b>SIA811DJ-T1-E3</b> Vishay / Siliconix MOSFET P-CH 20V 4.5A SC70-6</p>	 <p><b>SIA814DJ-T1-GE3</b> Electro-Films (EFI) / Vishay MOSFET N-CH 30V 4.5A SC70-6</p>	 <p><b>SIA811DJ-T1</b> VISHAY SIA811DJ-T1 VISHAY</p>	 <p><b>SIA811DJ-T1-GE3</b> Vishay / Siliconix MOSFET P-CH 20V 4.5A SC70-6</p>

### heiße Teile

Mehr

 SIA4528-470K	 SIA453EDJ-T1-GE3	 SIA453EDJ-T1-GE3	 SIA456DJ-T1-GE3	 SIA456DJ-T1-GE3
 SIA483DJ-T1-GE3	 SIA483DJ-T1-GE3	 SIA513DJ-T1-E3	 SIA517DJ-T1-GE3	 SIA517DJ-T1-GE3
 SIA517DJ-T4-GE3	 SIA519EDJ-T1-GE3	 SIA519EDJ-T1-GE3	 SIA533EDJ-T1-GE3	 SIA533EDJ-T1-GE3
 SIA778DJ-T1-GE3	 SIA778DJ-T1-GE3	 SIA811ADJ-T1-GE3	 SIA811ADJ-T1-GE3	 SIA811DJ-T1
 SIA811DJ-T1-E3	 SIA811DJ-T1-E3	 SIA811DJ-T1-GE3	 SIA811DJ-T1-GE3	 SIA813DJ-T1-GE3
 SIA814DJ-T1-GE3	 SIA814DJ-T1-GE3	 SIA906EDJ-T1-GE3	 SIA906EDJ-T1-GE3	 SIA906EDJ-T4-GE3
 SIA907EDJT	 SIA907EDJT-T1-GE3	 SIA907EDJT-T1-GE3	 SIA907EDJT-T4-GE3	 SIA910EDJ-T1-GE3
 SIA910EDJ-T1-GE3	 SIA911ADJ-T1-GE3	 SIA911ADJ-T1-GE3	 SIA911ADJ-T5-GE3	 SIA911DJ-T1-E3
 SIA911DJ-T1-E3	 SIA911DJ-T1-GE3	 SIA911DJ-T1-GE3	 SIA911DJ-T5-GE3	 SIA911EDJ-T1-GE3
 SIA911EDJ-T1-GE3	 SIA912DJ	 SIA912DJ-T1-GE3	 SIA912DJ-T1-GE3	 SIA913ADJ-T1-GE3

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